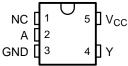
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#### **FEATURES**

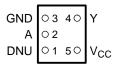
- Available in the Texas Instruments
  NanoStar<sup>™</sup> and NanoFree<sup>™</sup> Packages
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Sub-1-V Operable
- Max t<sub>pd</sub> of 2.5 ns at 1.8 V
- Low Power Consumption, 10-μA Max I<sub>CC</sub>
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

# DBV OR DCK PACKAGE (TOP VIEW)



NC - No internal connection

# YEA, YEP, YZA, OR YZP PACKAGE (BOTTOM VIEW)



DNU - Do not use

#### **DESCRIPTION/ORDERING INFORMATION**

This single inverter buffer/driver is operational at 0.8-V to 2.7-V  $V_{CC}$ , but is designed specifically for 1.65-V to 1.95-V  $V_{CC}$  operation.

The output of the SN74AUC1G06 is open drain and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions.

NanoStar<sup>™</sup> and NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING (2)
	NanoStar™ – WCSP (DSBGA) 0.17-mm Small Bump – YEA		SN74AUC1G06YEAR	
	NanoFree™ – WCSP (DSBGA) 0.17-mm Small Bump – YZA (Pb-free)	Tape and reel	SN74AUC1G06YZAR	UT
-40°C to 85°C	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP	rape and reer	SN74AUC1G06YEPR	01_
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)		SN74AUC1G06YZPR	
	SOT (SOT-23) – DBV	Tape and reel	SN74AUC1G06DBVR	U06_
	SOT (SC-70) – DCK	Tape and reel	SN74AUC1G06DCKR	UT_

<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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<sup>(2)</sup> DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site. YEA/YZA, YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, · = Pb-free).

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### **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

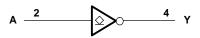
This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

For more information about AUC Little Logic devices, please refer to the TI application report, *Applications of Texas Instruments AUC Sub-1-V Little Logic Devices*, literature number SCEA027.

#### **FUNCTION TABLE**

INPUT A	OUTPUT Y
Н	L
L	Н

#### **LOGIC DIAGRAM (POSITIVE LOGIC)**



### Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	3.6	V
VI	Input voltage range <sup>(2)</sup>		-0.5	3.6	V
Vo	Output voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V <sub>CC</sub> or GND			±100	mA
		DBV package		206	
0	Declare the world in a decree (3)	DCK package		252	0000
$\theta_{JA}$	Package thermal impedance (3)	YEA/YZA package		154	°C/W
		YEP/YZP package		132	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.



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## Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		0.8	2.7	V
		$V_{CC} = 0.8 \text{ V}$	V <sub>CC</sub>		
$V_{IH}$	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$		V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		
		$V_{CC} = 0.8 V$		0	
$V_{IL}$	Low-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		0.35 × V <sub>CC</sub>	V
		$V_{CC}$ = 2.3 V to 2.7 V		0.7	
$V_{I}$	Input voltage		0	3.6	V
Vo	Output voltage		0	3.6	V
		$V_{CC} = 0.8 \text{ V}$		0.7	
		V <sub>CC</sub> = 1.1 V		3	
$I_{OL}$	Low-level output current	$V_{CC} = 1.4 \text{ V}$		5	mA
		V <sub>CC</sub> = 1.65 V		8	
		$V_{CC} = 2.3 \text{ V}$		9	
		$V_{CC} = 0.8 \text{ V to } 1.6 \text{ V}$		20	
$\Delta t/\Delta v$	Input transition rise or fall rate	V <sub>CC</sub> = 1.65 V		10	ns/V
		V <sub>CC</sub> = 2.3 V		5	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP(1) MAX	UNIT
	I <sub>OL</sub> = 100 μA	0.8 V to 2.7 V	0.2	
	I <sub>OL</sub> = 0.7 mA	0.8 V	0.25	
W	I <sub>OL</sub> = 3 mA	1.1 V	0.3	V
V <sub>OL</sub>	I <sub>OL</sub> = 5 mA	1.4 V	0.4	V
	I <sub>OL</sub> = 8 mA	1.65 V	0.45	
	I <sub>OL</sub> = 9 mA	2.3 V	0.6	
I <sub>I</sub> A input	$V_I = V_{CC}$ or GND	0 to 2.7 V	±5	μΑ
I <sub>off</sub>	$V_I$ or $V_O = 2.7 \text{ V}$	0	±10	μΑ
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	0.8 V to 2.7 V	10	μΑ
C <sub>i</sub>	$V_I = V_{CC}$ or GND	2.5 V	3	pF

<sup>(1)</sup> All typical values are at  $T_A = 25$ °C.

### **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = ± 0.		V <sub>CC</sub> = ± 0.			<sub>C</sub> = 1.8 0.15 \		V <sub>CC</sub> = ± 0.		UNIT
	(INFOT)	(0011-01)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	Α	Υ	5	0.3	3.1	0.2	2.4	(1)	(1)	(1)	(1)	(1)	ns

<sup>(1)</sup> This information was not available at the time of publication.

### SN74AUC1G06 SINGLE INVERTER BUFFER/DRIVER WITH OPEN-DRAIN OUTPUT

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## **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		<sub>C</sub> = 1.8 : 0.15 \		V <sub>CC</sub> = 2.5 V ± 0.2 V		UNIT
	(INFOT)	(001701)	MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	Α	Y	0.5	1.6	2.5	0.2	1.8	ns

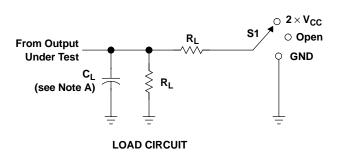
## **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 0.8 V TYP	V <sub>CC</sub> = 1.2 V TYP	V <sub>CC</sub> = 1.5 V TYP	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz	2	2	2	2	7	pF

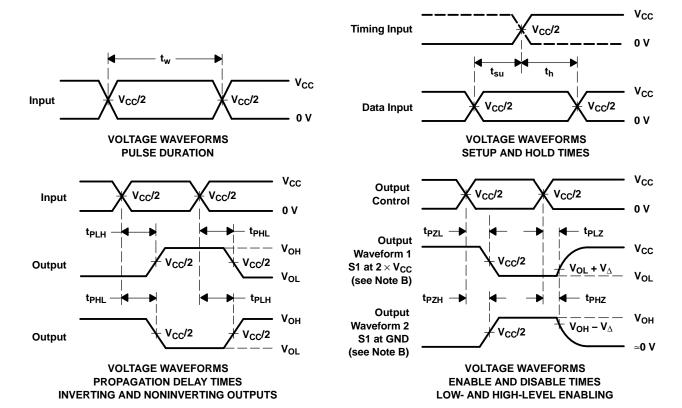


#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	$2 \times V_{CC}$
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

V <sub>CC</sub>	CL	R <sub>L</sub>	$oldsymbol{V}_\Delta$
0.8 V	15 pF	<b>2 k</b> Ω	0.1 V
1.2 V $\pm$ 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.5 V ± 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.8 V ± 0.15 V	15 pF	<b>2 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	15 pF	<b>2 k</b> Ω	0.15 V
1.8 V $\pm$ 0.15 V	30 pF	1 kΩ	0.15 V
2.5 V $\pm$ 0.2 V	30 pF	500 Ω	0.15 V



- NOTES: A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{O}$  = 50  $\Omega$ , slew rate  $\geq$  1 V/ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





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#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74AUC1G06DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G06DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G06DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G06DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G06YEAR	ACTIVE	WCSP	YEA	5	3000	TBD	SNPB	Level-1-260C-UNLIM
SN74AUC1G06YEPR	ACTIVE	WCSP	YEP	5	3000	TBD	SNPB	Level-1-260C-UNLIM
SN74AUC1G06YZAR	ACTIVE	WCSP	YZA	5	3000	Pb-Free (RoHS)	SNAGCU	Level-1-260C-UNLIM
SN74AUC1G06YZPR	ACTIVE	WCSP	YZP	5	3000	Pb-Free (RoHS)	SNAGCU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

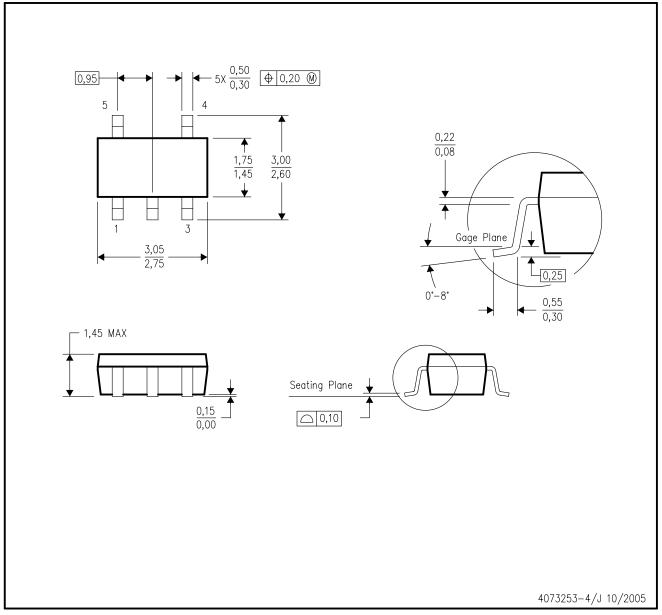
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## DBV (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



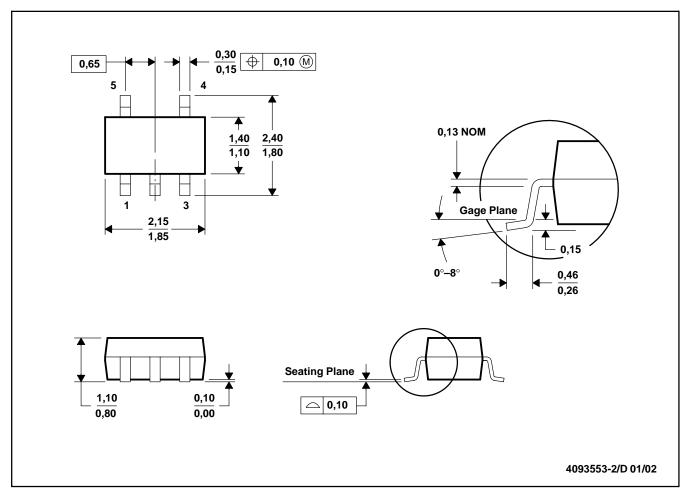
NOTES:

- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.



### DCK (R-PDSO-G5)

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

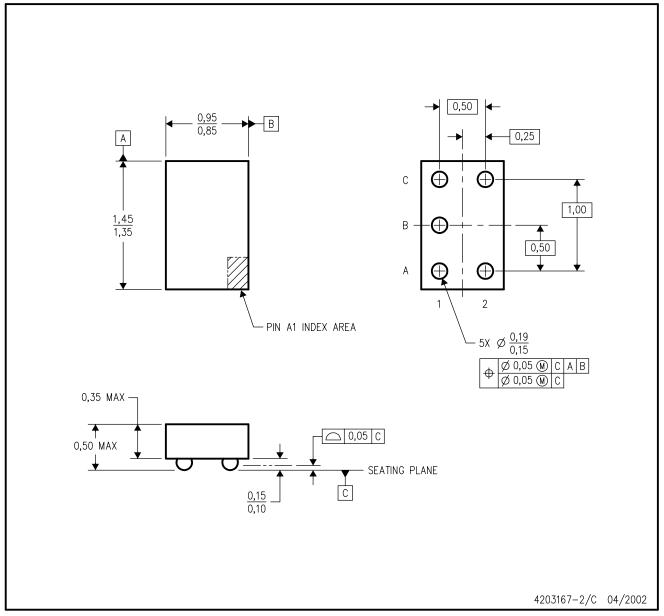
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion.

D. Falls within JEDEC MO-203

## YEA (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

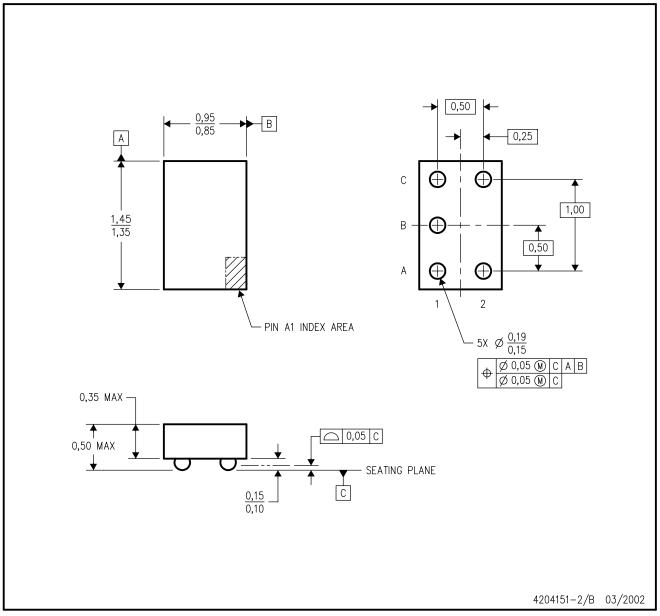
- B. This drawing is subject to change without notice.
- C. NanoStar  $\mathbf{M}$  package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is tin-lead (SnPb). Refer to the 5 YZA package (drawing 4204151) for lead-free.

NanoStar is a trademark of Texas Instruments.



## YZA (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

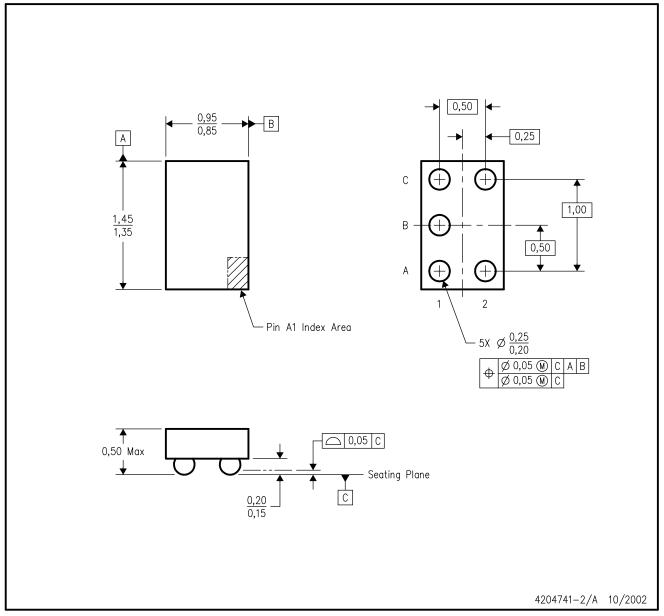
- B. This drawing is subject to change without notice.
- C. NanoFree  $^{\text{TM}}$  package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is lead-free. Refer to the 5 YEA package (drawing 4203167) for tin-lead (SnPb).

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## YZP (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

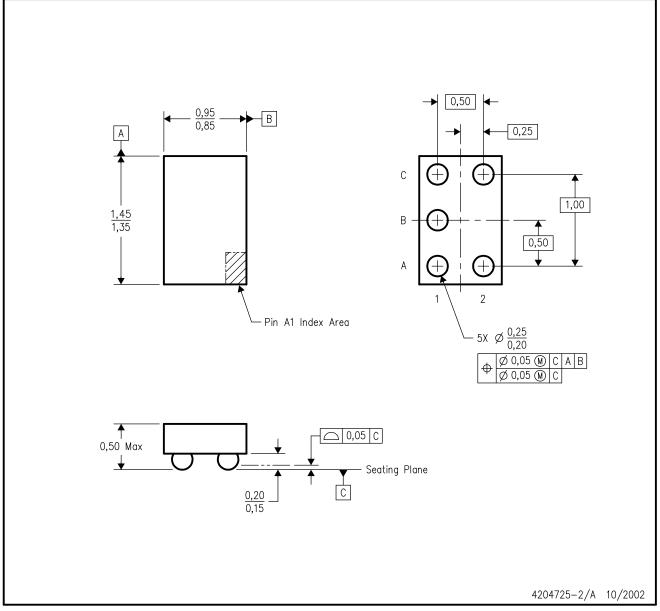
- B. This drawing is subject to change without notice.
- C. NanoFree  $^{\text{TM}}$  package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

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# YEP (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. NanoStar  $\mathbf{M}$  package configuration.
- D. This package is tin-lead (SnPb). Refer to the 5 YZP package (drawing 4204741) for lead-free.

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